Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.145 inches and 0.175 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.075 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case and burn in

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

14.0 noise voltage and 33.0 noise voltage

Current Rating Per Characteristic:

5.00 microamperes forward current, average peak

Power Rating Per Characteristic:

100.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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